CBT3306

Dual bus switch

Rev. 7 — 1 May 2012

Product data sheet

1. General description

The CBT3306 dual FET bus switch features independent line switches. Each switch is disabled when the associated output enable (nOE) input is HIGH.

The CBT3306 is characterized for operation from -40 °C to +85 °C.

2. Features and benefits

- \blacksquare 5 Ω switch connection between two ports
- TTL-compatible input levels
- Multiple package options
- Latch-up protection exceeds 100 mA per JESD78B
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ CDM JESD22-C101D exceeds 1000 V

3. Ordering information

Table 1. Ordering information

Type number	Package	Package										
	Name	Description	Version									
CBT3306D	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1									
CBT3306PW	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 4.4 mm	SOT530-1									
CBT3306GT	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1									
CBT3306GM	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 \times 1.6 \times 0.5 mm	SOT902-2									

4. Marking

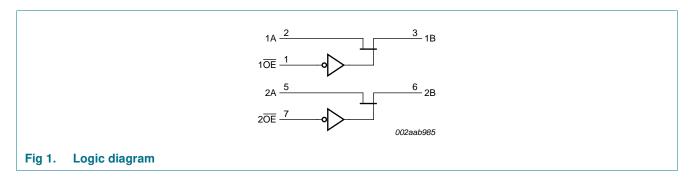
Table 2. Marking codes

Type number	Marking code	
CBT3306D	CBT3306	
CBT3306PW	3306	
CBT3306GT	F06	
CBT3306GM	F06	



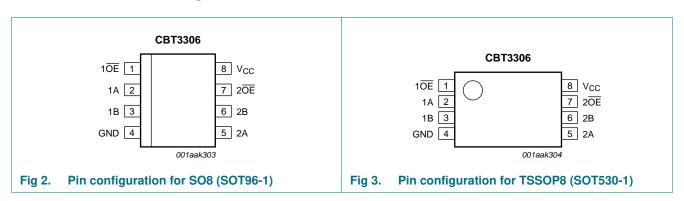
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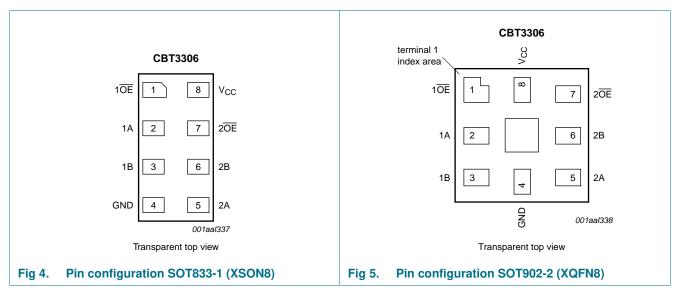
5. Functional diagram



6. Pinning information

6.1 Pinning





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6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
1 OE , 2 OE	1, 7	output enable input
1A, 2A	2, 5	data input/output (A port)
1B, 2B	3, 6	data input/output (B port)
GND	4	ground (0 V)
V _{CC}	8	positive supply voltage

7. Functional description

Table 4. Function selection[1]

Input nOE	Input/output
nOE	nA, nB
L	nA = nB
Н	Z

^[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). \Box $T_{amb} = -40$ °C to +85 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
V _I	input voltage		[<u>2</u>] -0.5	+7.0	V
Io	output current		-	128	mA
I _{IK}	input clamping current	$V_{I/O} = 0 V$	-50	-	mA
T _{stg}	storage temperature		-65	+150	°C

^[1] Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Section 9. is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

9. Recommended operating conditions

Table 6. Operating conditions

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

	-					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		4.5	-	5.5	V
V_{IH}	HIGH-level input voltage		2.0	-	-	V
V_{IL}	LOW-level input voltage		-	-	0.8	V
T _{amb}	ambient temperature	operating in free air	-40	-	+85	°C

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^[2] The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

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10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

$\begin{tabular}{l l} Symbol \\ \hline V_{IK} \\ \hline I_I \\ \hline I_{CC} \\ \hline V_{pass} \\ \hline ΔI_{CC} \\ \hline \end{tabular}$	Parameter	Conditions		-4	Unit		
				Min	Typ[1]	Max	
V_{IK}	input clamping voltage	$V_{CC} = 4.5 \text{ V}; I_I = -18 \text{ mA}$		-	-	-1.2	V
I _I	input leakage current	$V_{CC} = 5.5 \text{ V}; V_{I} = \text{GND or } 5.5 \text{ V}$		-	-	±1	μΑ
I _{CC}	supply current	V_{CC} = 5.5 V; I_O = 0 mA; V_I = V_{CC} or GND		-	-	3	μΑ
V_{pass}	pass voltage	output HIGH; $V_I = V_{CC} = 5.0 \text{ V}$; $I_O = -100 \mu A$		3.6	3.9	4.2	V
Δl _{CC}	additional supply current	per input pin; V _{CC} = 5.5 V; one input at 3.4 V, other inputs at V _{CC} or GND	[2]	-	-	2.5	mA
Cı	input capacitance	control pin; V _I = 3 V or 0 V		-	3.15	-	pF
$C_{\text{io(off)}}$	off-state input/output capacitance	port off; $V_1 = 3 \text{ V or } 0 \text{ V; } n\overline{OE} = V_{CC}$		-	6.45	-	pF
R _{ON}	ON resistance	$V_{CC} = 4.5 \text{ V}; V_I = 0 \text{ V}; I_I = 64 \text{ mA}$	[3]	-	3.4	5	Ω
		$V_{CC} = 4.5 \text{ V}; V_I = 0 \text{ V}; I_I = 30 \text{ mA}$	[3]	-	3.4	5	Ω
		$V_{CC} = 4.5 \text{ V}; V_I = 2.4 \text{ V}; I_I = 15 \text{ mA}$	[3]	-	6.8	15	Ω

^[1] All typical values are at V_{CC} = 5 V, T_{amb} = 25 °C.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 8.

Symbol	Parameter	Conditions		-40	Unit		
				Min	Тур	Max	
t _{pd}	propagation delay	nA, nB to nB, nA; see Figure 6	[2]	-	-	0.25	ns
		$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$					
t _{en}	enable time	nOE to nA, nB; see Figure 7	[2]	1.0	-	5.0	ns
		$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$					
t _{dis}	disable time	nOE to nA, nB; see Figure 7	[2]	1.0	-	5.0	ns
		$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$					

^[1] The propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

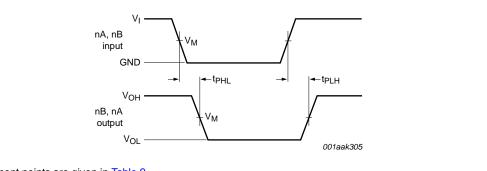
^[2] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

^[3] Measured by the voltage drop between the nA and the nB terminals at the indicated current through the switch. ON resistance is determined by the lowest voltage of the two (nA, nB) terminals.

 $[\]begin{array}{ll} [2] & t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}. \\ & t_{en} \text{ is the same as } t_{PZL} \text{ and } t_{PZH}. \\ & t_{dis} \text{ is the same as } t_{PLZ} \text{ and } t_{PHZ}. \end{array}$

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12. Waveforms



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 6. The data input (nA, nB) to output (nB, nA) propagation delay times

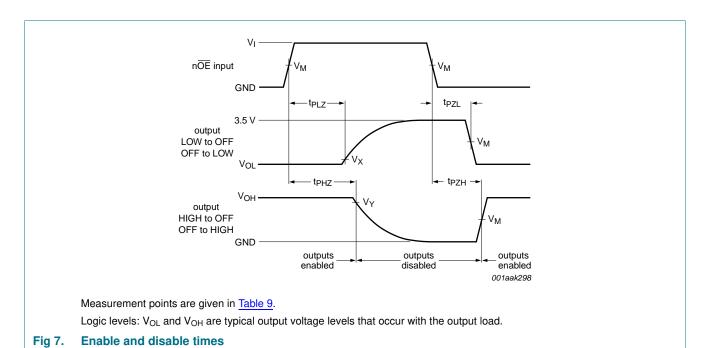
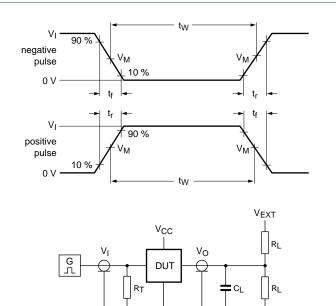


Table 9. Measurement points

Supply voltage	Input		Output						
V _{CC}	V _I V _M		V _M	V _X	V _Y				
V_{CC} = 5.0 V \pm 0.5 V	GND to 3.0 V	1.5 V	1.5 V	V _{OL} + 0.3 V	$V_{OH} - 0.3 V$				

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13. Test information



001aae331

Test data is given in Table 10.

All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz; $Z_0 = 50~\Omega$.

The outputs are measured one at a time with one transition per measurement.

Definitions for test circuit:

 R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

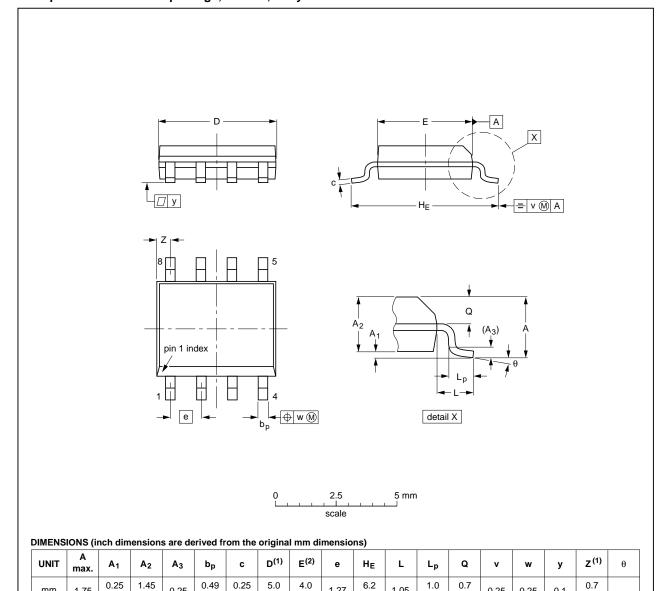
Table 10. Test data

Supply voltage	Input L		Load		V _{EXT}			
	V_l t_r , t_f		CL	R _L	t _{PLH} , t _{PHL}	t_{PLZ} , t_{PZL}	t _{PHZ} , t _{PZH}	
$V_{CC}=5.0~V\pm0.5~V$	GND to 3.0 V	\leq 2.5 ns	50 pF	500Ω	open	7.0 V	open	

14. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



mm

inches

1.75

0.069

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.36

0.19

0.019 0.0100

0.014 0.0075

4.8

0.20

3.8

0.16

0.15

0.25

0.01

1.25

0.057

0.049

0.10

0.010

0.004

2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
	SOT96-1	076E03	MS-012				99-12-27 03-02-18

1.27

0.05

1.05

0.041

0.4

0.039

0.016

0.6

0.028

0.024

5.8

0.244

0.228

0.25

0.01

0.25

0.01

Fig 9. Package outline SOT96-1 (SO8)

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0.3

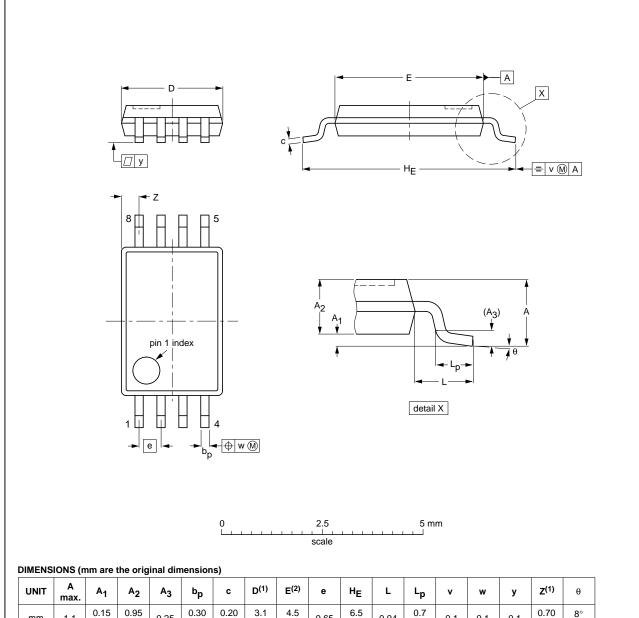
0.028

0.004

0°

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 4.4 mm

SOT530-1



UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	٧	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.85	0.25	0.30 0.19	0.20 0.13	3.1 2.9	4.5 4.3	0.65	6.5 6.3	0.94	0.7 0.5	0.1	0.1	0.1	0.70 0.35	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN	ISSUE DATE		
	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
SOT530-1		MO-153				00-02-24 03-02-18	
						03.02-10	—

Fig 10. Package outline SOT530-1 (TSSOP8)

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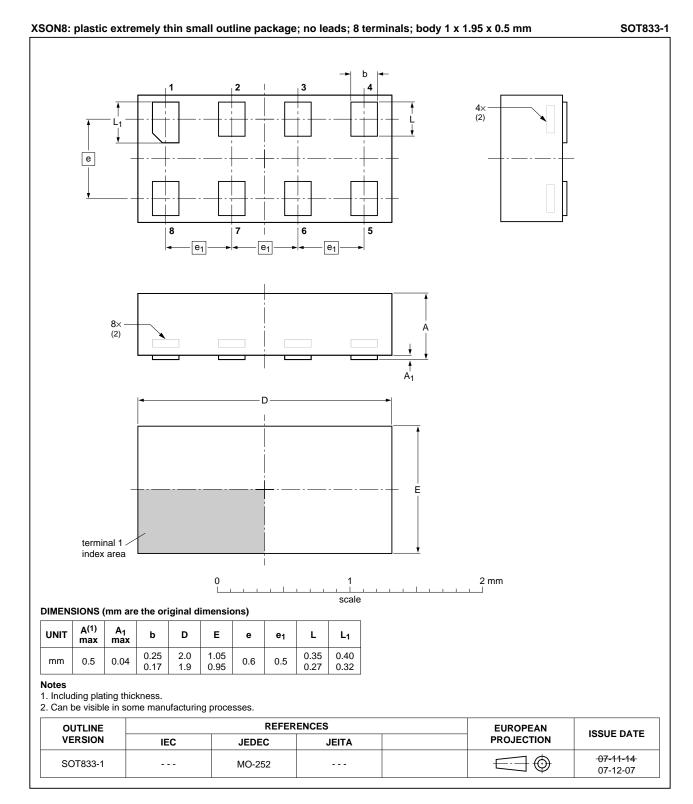


Fig 11. Package outline SOT833-1 (XSON8)

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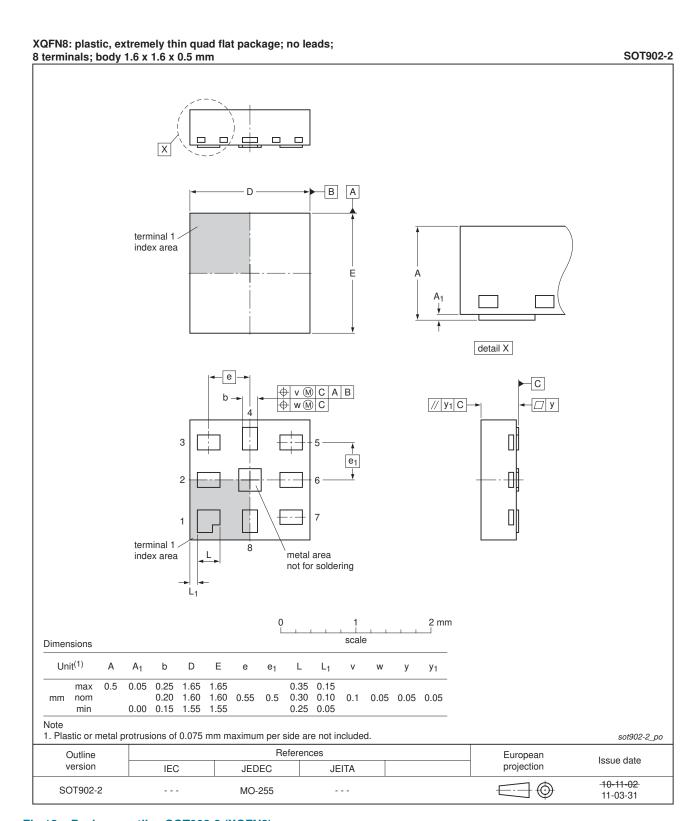


Fig 12. Package outline SOT902-2 (XQFN8)

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15. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
ESD	ElectroStatic Discharge
FET	Field Effect Transistor
НВМ	Human Body Model
PRR	Pulse Rate Repetition
TTL	Transistor-Transistor Logic

16. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
CBT3306 v.7	20120501	Product data sheet	-	CBT3306 v.6		
Modifications:	For type number CBT3306GM the sot code has changed to SOT902-2.					
CBT3306 v.6	20111122	Product data sheet	-	CBT3306 v.5		
Modifications:	Legal pages updated.					
CBT3306 v.5	20100325	Product data sheet	-	CBT3306 v.4		
CBT3306 v.4	20100218	Product data sheet	-	CBT3306 v.3		
CBT3306 v.3	20091014	Product data sheet	-	CBT3306 v.2		
CBT3306 v.2	20051117	Product data sheet	-	CBT3306 v.1		
CBT3306 v.1	20011108	Product data	-	-		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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